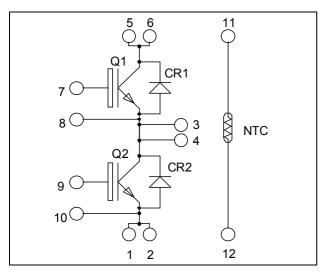
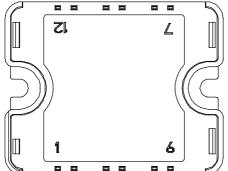


Phase leg NPT IGBT Power Module

$$V_{CES} = 600V$$

 $I_{C} = 30A$ @ $T_{C} = 80^{\circ}C$





Pins 1/2; 3/4; 5/6 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- **RoHS Compliant**

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	42	
	Continuous Conector Current	$T_C = 80^{\circ}C$	30	Α
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	100	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	140	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	60A@500V	

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25$ °C			250	^
		$V_{CE} = 600V$	$T_j = 125$ °C			500 μ2	μΑ
V _{CE(on)}		$V_{GE} = 15V$	$T_j = 25^{\circ}C$	1.7	2.0	2.45	V
		$I_C = 30A$	$T_j = 125$ °C		2.2		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1 \text{mA}$		4		6	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

•	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		1350			
C_{oes}	Output Capacitance	$V_{CE} = 25V$		193		pF	
C_{res}	Reverse Transfer Capacitance	f = 1MHz		120			
Q_{g}	Total gate Charge	$V_{GE} = 15V$		99		nC	
Q_{ge}	Gate – Emitter Charge	$V_{Bus} = 300V$		10			
Q_{gc}	Gate – Collector Charge	$I_C=30A$		60			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch		30			
$T_{\rm r}$	Rise Time	$V_{GE} = 15V$		12		ns	
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 400V$ $I_{C} = 30A$		80			
T_{f}	Fall Time	$R_G = 6.8\Omega$		15			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (125°C)		32		
$T_{\rm r}$	Rise Time	$V_{GE} = 15V$ $V_{Bus} = 400V$ $I_{C} = 30A$ $R_{G} = 6.8\Omega$			12		ns
$T_{d(off)}$	Turn-off Delay Time				90		
$T_{\rm f}$	Fall Time				21		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$	$T_j = 125$ °C		0.3		I
E_{off}	Turn-off Switching Energy	$I_C = 30A$ $R_G = 6.8\Omega$	$T_j = 125$ °C		0.8		mJ

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_j = 25^{\circ}C$			25	۸
			$T_j = 125$ °C			500	μA
I_F	DC Forward Current		$Tc = 80^{\circ}C$		25		A
		$I_F = 25A$			1.8	2.2	
$V_{\rm F}$	Diode Forward Voltage	$I_F = 50A$			2.2		V
		$I_F = 25A$	$T_j = 125$ °C		1.6		
t_{rr}	Reverse Recovery Time	$I_F = 25A$	$T_j = 25$ °C		30		ns
r _{rr}				$V_{R} = 400V$ $T_{j} = 125^{\circ}C$		175	
Q _{rr}	Reverse Recovery Charge	$di/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		55		пC
			$T_{j} = 125^{\circ}C$		485		IIC.



Thermal and package characteristics

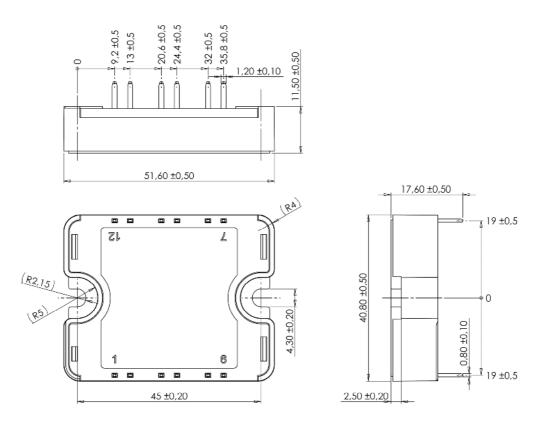
Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance IGBT Diode	I	GBT			0.9	°C/W
		Diode			1.4	C/ W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		4000			V	
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque To	heatsink	M4	2	•	3	N.m
Wt	Package Weight			•	80	g	

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

_	Symbol	Characteristic	Min	Typ	Max	Unit	
	R ₂₅	Resistance @ 25°C		50		kΩ	
	B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K	

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature} \\ R_T: \text{ Thermistor value at T}$$

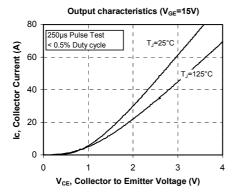
SP1 Package outline (dimensions in mm)

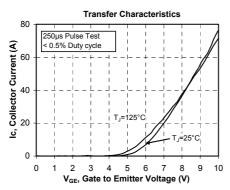


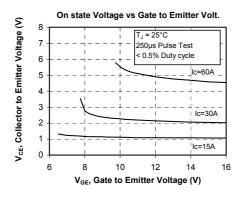
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

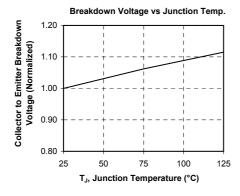


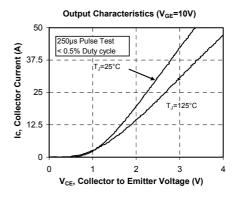
Typical Performance Curve

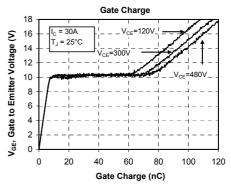


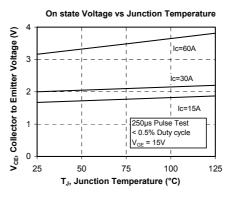


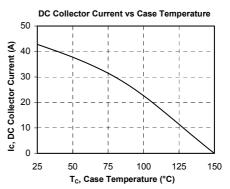






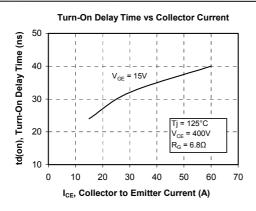


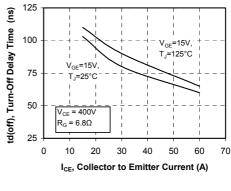


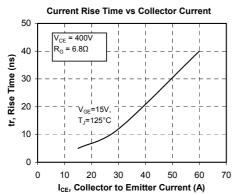


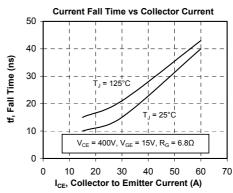


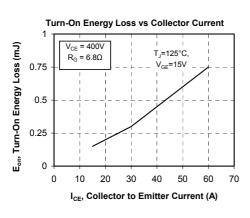
Turn-Off Delay Time vs Collector Current

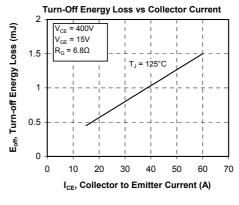


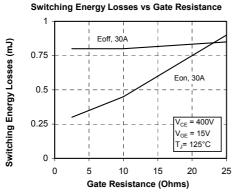


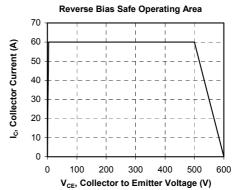




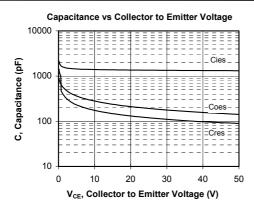


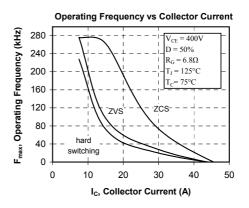


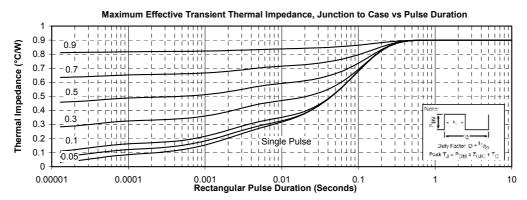












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